

# ZXSBMR16PT8

## MR16: Schottky bridge rectifier plus freewheel diode

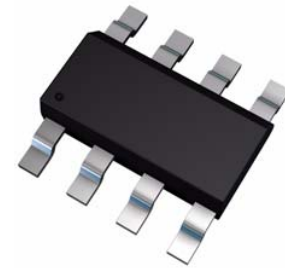
### Summary

Schottky Bridge and Freewheel diode for use in MR16 LED Drive

Internal Ambient Temperature = 90°C MAX\*

$V_R = 13.2V_{RMS}$ ;  $I_F = 0.4A_{AVG}$ ;  $I_R = 10\mu A$

\*within MR16 circuit enclosure



SM8

### Description

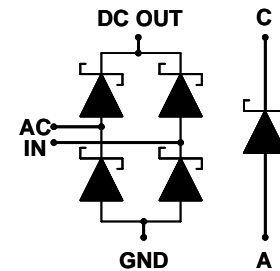
This low leakage Schottky bridge and freewheel diode have been specifically designed for the MR16 LED driver solution alongside ZXLD1350E5 as described in Design Note DN86.

### Key benefits

- Compact surface mount solution and reduced component count in MR16 LED drive circuit

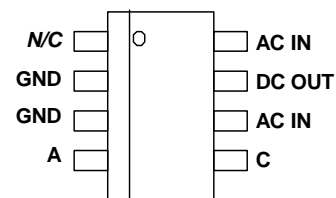
### Features

- Optimized bridge and freewheel diode for use in MR16 LED diode circuitry
- Low VF and low reverse leakage current



### Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXSBMR16PT8TA	7	12	1000



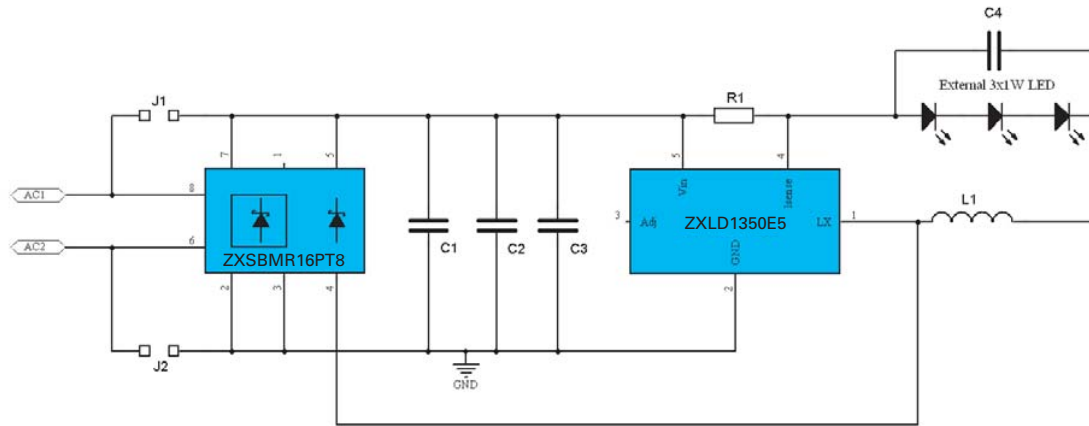
Pinout - top view

### Device marking

ZXSB  
MR16P

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## Application Schematic from DN86



## Absolute maximum ratings

Parameter	Symbol	Value	Unit
<b>Bridge</b>			
Maximum repetitive reverse voltage	$V_{RRM}$	40	V
Maximum RMS bridge input voltage	$V_{RMS}$	13.2	V
Average rectified forward current <sup>(a)(b)</sup>	$I_{F(AV)}$	0.4	A
Peak repetitive forward current	$I_{FPK}$	3.5	A
Non repetitive forward current $t \leq 100\mu s$	$I_{FSM}$	13	A
$t \leq 10ms$		3.5	A
<b>Package</b>			
Power dissipation at $T_{amb}=25^{\circ}C^{(a)}$	$P_D$	1	W
Storage temperature range	$T_{stg}$	-55 to +150	$^{\circ}C$
Junction temperature forward dissipation only	$T_j$	150	$^{\circ}C$
Junction temperature reverse dissipation <sup>(a)(b)(c)</sup>	$T_j$	125	$^{\circ}C$
MR16 LED internal ambient temperature <sup>(d)</sup>	$T_{amb}$	90	$^{\circ}C$

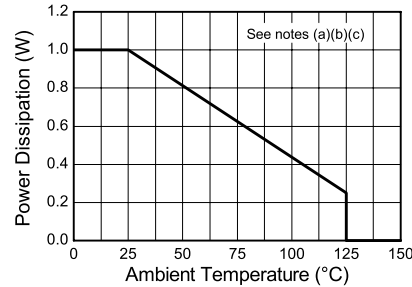
## Thermal characteristics

Parameter	Symbol	Limit	Unit
Junction to ambient <sup>(a)</sup>	$R_{\theta JA}$	125	$^{\circ}C/W$

### NOTES:

- (a) For a bridge mounted on 1.6mm FR4 PCB with minimum copper pads and track dimensions in still air.
- (b) Supply 12V RMS with capacitive bridge load.
- (c) Maximum bridge operating junction temperature must be reduced with increased reverse bias voltage to maintain unconditional thermal stability.
- (d) Refer to Design Note DN86

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Package Thermal Characteristic

Electrical characteristics per diode (at  $T_{amb} = 25^{\circ}\text{C}$  unless otherwise stated)

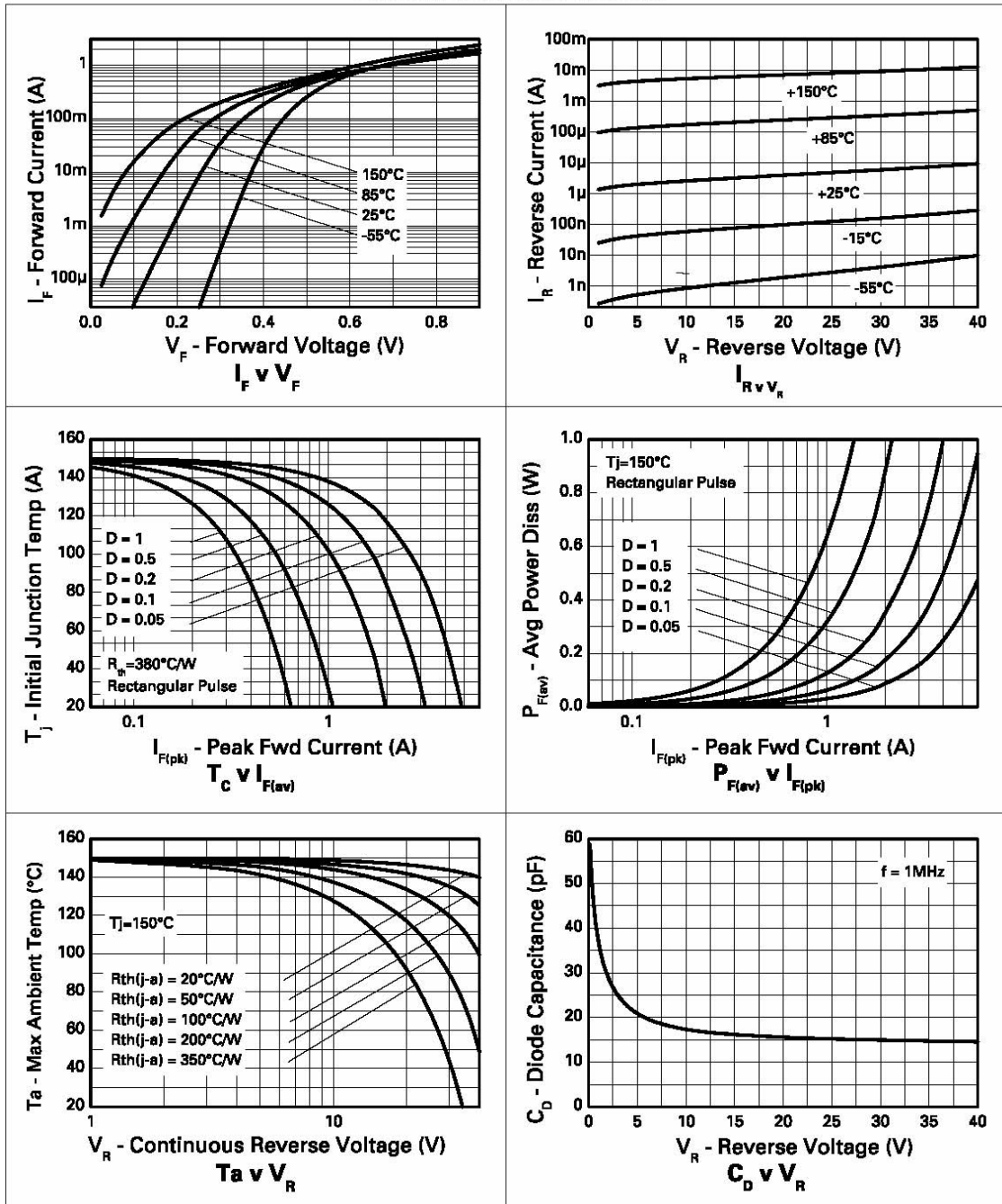
Schottky diode characteristics						
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse breakdown voltage	$V_{(BR)R}$	40			V	$I_R=200\mu\text{A}$
Forward voltage	$V_F$		305	360	mV	$I_F=50\text{mA}^{(*)}$
			355	410	mV	$I_F=100\text{mA}^{(*)}$
			405	470	mV	$I_F=250\text{mA}^{(*)}$
			485	550	mV	$I_F=500\text{mA}^{(*)}$
			570	660	mV	$I_F=750\text{mA}^{(*)}$
			640	750	mV	$I_F=1\text{A}^{(*)}$
			415		mV	$I_F=500\text{mA}^{(*)}, T_a = 100^{\circ}\text{C}$
Reverse current	$I_R$		6	10	$\mu\text{A}$	$V_R=30\text{V}$
			370		$\mu\text{A}$	$V_R=30\text{V}, T_a = 85^{\circ}\text{C}$
Diode capacitance	$C_D$		16		pF	$f=1\text{MHz}, V_R=30\text{V}$
Reverse recovery time	$t_{rr}$		3		ns	Switched from $I_F = 500\text{mA}$ to $V_R = 5.5\text{V}$ Measured @ $I_R 50\text{mA}$ . $di/dt = 500\text{mA/ns}$ . $R_{source} = 6\Omega; R_{load} = 10\Omega$
Reverse recovery charge	$Q_{rr}$		210		pC	

**NOTES:**

(\*) Measured under pulsed conditions. Pulse width = 300 $\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

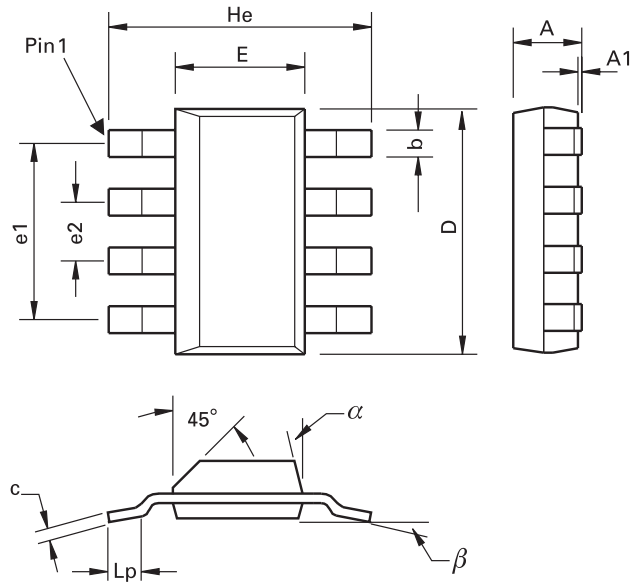
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## Typical characteristics single diode



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## Package outline - SM8



DIM	Millimeters			Inches			DIM	Millimeters			Inches		
	Min.	Max.	Typ.	Min.	Max.	Typ.		Min.	Max.	Typ.	Min.	Max.	Typ.
A	-	1.7	-	-	0.067	-	e1	-	-	4.59	-	-	0.1807
A1	0.02	0.1	-	0.0008	0.004	-	e2	-	-	1.53	-	-	0.0602
b	-	-	0.7	-	-	0.0275	He	6.7	7.3	-	0.264	0.287	-
c	0.24	0.32	-	0.009	0.013	-	Lp	0.9	-	-	0.035	-	-
D	6.3	6.7	-	0.248	0.264	-	α	-	15°	-	-	15°	-
E	3.3	3.7	-	0.130	0.145	-	β	-	-	10°	-	-	10°

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

# ZXSBMR16PT8

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